



Attorney's Docket No.: 07977-010005 / US2941D1D1D1

2822 \$

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Kusumoto, et al. Art Unit : Unknown
Serial No.: 09/941,367 Examiner : Unknown
Filed : August 28, 2001
Title : METHOD FOR PRODUCING INSULATED GATE THIN FILM
SEMICONDUCTOR DEVICE

Commissioner for Patents
Washington, D.C. 20231

TRANSMITTAL LETTER AND PETITION FOR AUTOMATIC EXTENSION

Correspondence relating to this application is enclosed.
The required fees are computed below. Please apply any charges
not covered, or any credits, to Deposit Account No. 06-1050.

Total Claims	108	-	80	=	28	\$504
Independent	23	-	16	=	7	\$588
First Presentation of Multiple Dependent Claims						\$280
TOTAL FEE DUE						\$1372

A check for \$1372 is attached.

Respectfully submitted,

Date:

Oct. 10, 2001

Bing Ai

Reg. No. 43,312

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CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR §1.8(a) that this
correspondence is being deposited with the
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October 10, 2001

Date of Deposit

Signature

Norman Green

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Attorney's Docket No.: 0797-310005 / US2941D1D1D1

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PRELIMINARY AMENDMENT

Prior to examination, please amend the application as follows:

In the claims:

Add claims 21-30 as follows:

B¹
-- 21. (New) A method for manufacturing a semiconductor device, said method comprising the steps of:
forming a semiconductor layer over a substrate;
irradiating said semiconductor layer with a CW laser beam to crystallize said semiconductor layer; and
patterning the crystallized semiconductor layer to form an active layer including a channel region,

CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR §1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, Washington, D.C. 20231.

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